MOSPEC

FRF1220K

Switchmode
Full Plastic Dual Schottky Barrier Power Rectifiers

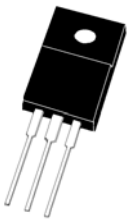
Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- ∗Glass Passivated chip junctions
- ∗Low Reverse Leakage Current
- ∗Fast Switching for High Efficiency
- ∗150℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction
- ∗Low Forward Voltage , High Current Capability
- ∗Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

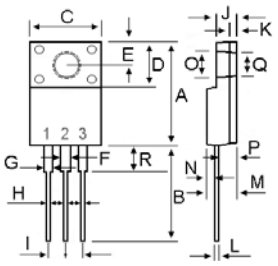
∗*In compliance with EU RoHs 2002/95/EC directives*

FAST RECOVERY RECTIFIERS

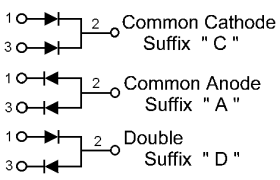
12 AMPERES
200 VOLTS



ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80



MAXIMUM RATINGS

Characteristic	Symbol	FRF1220K	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	6 12	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz, T_C=125℃)	I_{FM}	12	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	80	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	FRF1220K	Unit
Maximum Instantaneous Forward Voltage (I_F =6 Amp T_C = 25℃)	V_F	1.1	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	1 100	uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	35	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	55	pF

FRF1220K

FIG-1 TYPICAL FORWARD CHARACTERISITICS

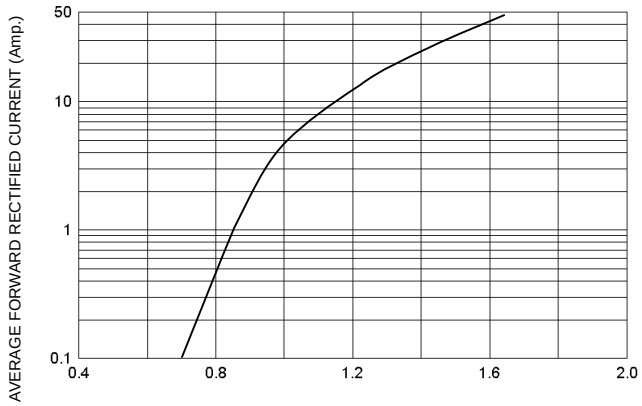


FIG-2 TYPICAL REVERSE CHARACTERISTICS

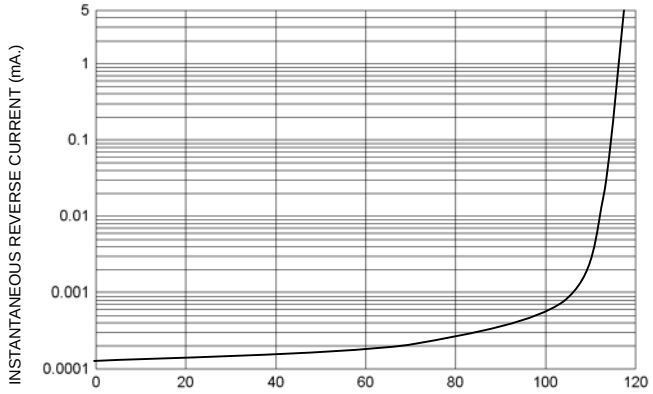


FIG-3 FORWARD CURRENT DERATING CURVE

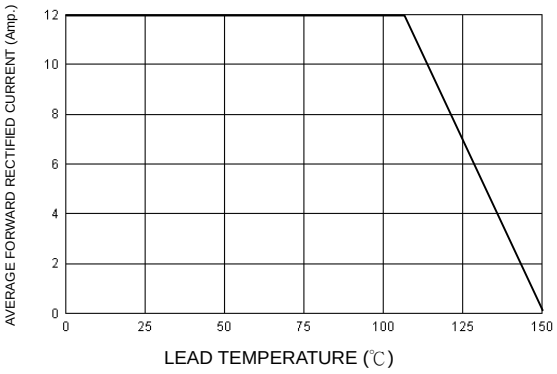


FIG-4 TYPICAL JUNCTION CAPACITANCE

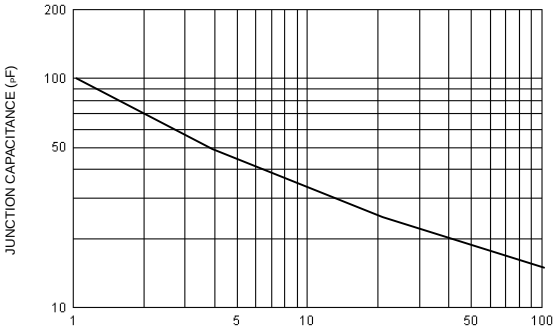
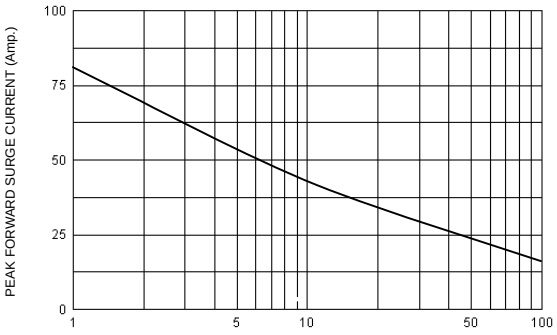
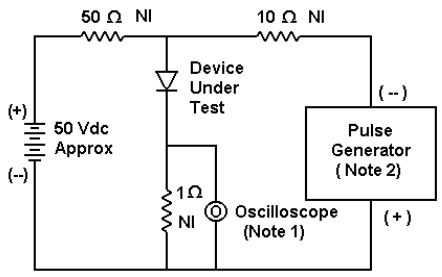
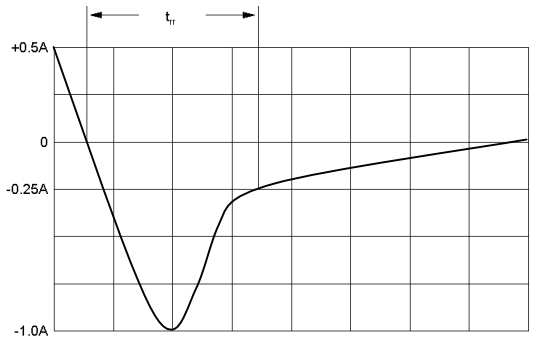


FIG-5 PEAK FORWARD SURGE CURRENT





Notes:
1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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